



SD103ATW

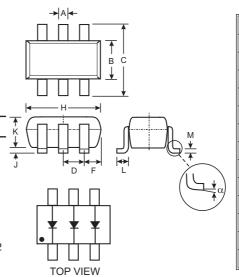
SURFACE MOUNT SCHOTTKY BARRIER DIODE ARRAY

Features

- Low Forward Voltage Drop
- Guard Ring Construction for Transient Protection
- Fast Switching
- Low Leakage Current
- Three Fully Isolated Schottky Diodes
- Lead Free/RoHS Compliant (Note 3)

Mechanical Data

- Case: SOT-363
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Polarity: See Diagram
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Marking: KLL (See Page 3)
- Ordering Information: (See Page 3)
- Weight: 0.006 grams (approx.)



SOT-363								
Dim	Min	Max						
Α	0.10	0.30						
В	1.15	1.35						
С	2.00	2.20						
D	0.65 Nominal							
F	0.30	0.40						
Н	1.80	2.20						
J	_	0.10						
K	0.90	1.00						
L	0.25	0.40						
М	0.10	0.25						
α	0°	8°						
All Dimensions in mm								

Maximum Ratings @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value				
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	40	V			
RMS Reverse Voltage	V _{R(RMS)}	28	V			
Forward Continuous Current (Note 1)	I _{FM}	350	mA			
Average Rectified Current (Note 1)	Io	175	mA			
Non-Repetitive Peak Forward Surge Current (Note 1) @ t ≤ 10ms	I _{FSM}	1.0	Α			
Power Dissipation (Note 4)	Pd	200	mW			
Thermal Resistance, Junction to Ambient Air (Note 4)	$R_{\theta JA}$	500	°C/W			
Operating and Storage Temperature Range	T _j , T _{STG}	-55 to +125	°C			

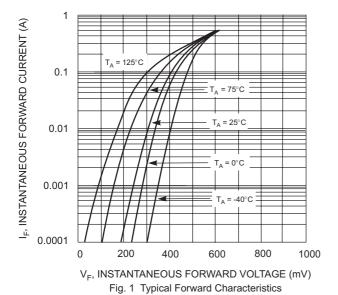
Electrical Characteristics @ T_A = 25°C unless otherwise specified

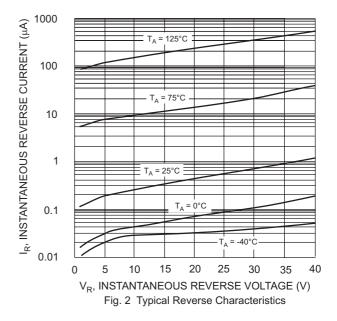
Characteristic		Min	Тур	Max	Unit	Test Condition		
Reverse Breakdown Voltage (Note 2)		40	_	_	V	I _{RS} = 100μA (pulsed)		
Forward Voltage Drop	V _F	_ _ _	0.27 0.32 0.36 0.44	0.37 0.50	V V V	I _F = 1mA I _F = 5mA I _F = 20mA I _F = 100mA		
Reverse Current (Note 2)	I _R		0.2 0.4	2.0 5.0	μ Α μ Α	V _R = 10V V _R = 30V		
Total Capacitance	Ст	_	50	_	pF	V _R = 0V, f = 1.0MHz		
Reverse Recovery Time	t _{rr}	_	10	_	ns	$I_F = I_R = 200 \text{mA},$ $I_{rr} = 0.1 \text{ x } I_R, R_L = 100 \Omega$		

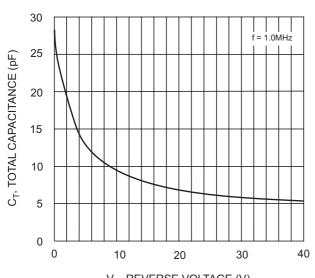
Notes: 1. This is the maximum rating of single Diode (D₁ or D₂ or D₃). In the case of using two or three diodes, the maximum ratings per diode are 75% of the ratings for single diode operation.

- 2. Short duration test pulse used to minimize self-heating effect.
- 3. No purposefully added lead.
- 4. Part mounted on FR-4 board with recommended pad layout, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.









(ME) 100 POWER DISSIPATION (#M) 0 0 25 50 75 100 125

 ${\rm V_{R},\,REVERSE\;VOLTAGE\;(V)}$ Fig. 3 Typ. Total Capacitance vs. Reverse Voltage

T_A, AMBIENT TEMPERATURE (°C) Fig. 4 Power Derating Curve

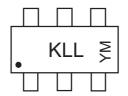


Ordering Information (Note 5)

Device	Packaging	Shipping			
SD103ATW-7-F	SOT-363	3000/Tape & Reel			

Notes: 5. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



KLL = Product Type Marking Code YM = Date Code Marking Y = Year ex: N = 2002

M = Month ex: 9 = September

Date Code Key

Year		2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code		N	Р	R	S	Т	U	V	W	Х	Υ	Z
Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

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